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BS IEC 60747-3:2013



BSI Standards Publication

Semiconductor devices

Part 3: Discrete devices: Signal,
switching and regulator diodes

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Part 3: Discrete devices: Signal, switching and regulator diodes**

**Dispositifs à semiconducteurs –
Partie 3: Dispositifs discrets: Diodes de signal, diodes de commutation et diodes
régulatrices**

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CONTENTS

FOREWORD.....	4
1 Scope.....	6
2 Normative references	6
3 Terms, definitions and graphical symbols	6
3.1 Signal and switching diodes	6
3.2 Voltage reference diodes and voltage regulator diodes.....	7
3.3 Current-regulator diodes.....	8
4 Letter symbols.....	9
4.1 General.....	9
4.2 Signal and switching diodes	9
4.2.1 Subscripts	9
4.2.2 List of letter symbols.....	9
4.3 Voltage reference diodes and voltage regulator diodes.....	10
4.3.1 Subscripts	10
4.3.2 List of letter symbols.....	10
4.4 Current-regulator diodes.....	10
4.4.1 Subscripts	10
4.4.2 List of letter symbols.....	11
5 Essential ratings and characteristics.....	11
5.1 General.....	11
5.2 Signal and switching diodes	11
5.2.1 Ratings (limiting values)	11
5.2.2 Characteristics	11
5.3 Voltage reference diodes and voltage regulator diodes.....	14
5.3.1 Ratings (limiting values)	14
5.3.2 Characteristics	14
5.4 Current-regulator diodes.....	16
5.4.1 Ratings (limiting values)	16
5.4.2 Characteristics	16
6 Measuring methods	17
6.1 General.....	17
6.2 Signal and switching diodes	17
6.2.1 Reverse current I_R	17
6.2.2 Forward voltage V_F	17
6.2.3 Total capacitance C_{tot}	18
6.2.4 Forward recovery time t_{fr} and peak forward recovery voltage V_{FRM}	19
6.2.5 Reverse recovery time (t_{rr}) and recovered charge (Q_r).....	20
6.2.6 Detector voltage efficiency η_V	21
6.2.7 Detector power efficiency η_p	22
6.2.8 Noise V_n , I_n	23
6.3 Voltage reference diodes and voltage regulator diodes.....	24
6.3.1 Working voltage V_Z	24
6.3.2 Differential resistance in the working current range r_Z	25
6.3.3 Temperature coefficient of working voltage α_{VZ}	25
6.3.4 Reverse current I_R	26
6.3.5 Forward voltage V_F	26